4

PJQ5458A-AU 60V N-Channel Enhancement Mode MOSFET

Current

Voltage

Features

PAN

CONDUCTOR

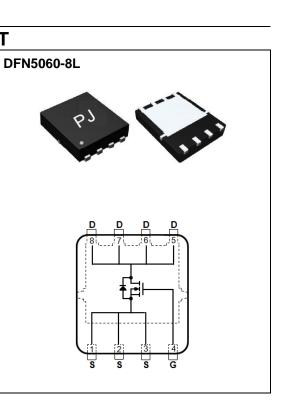
• R_{DS(ON)}, V_{GS}@10V, I_D@8A<50mΩ

60 V

- $R_{DS(ON)}$, V_{GS} @4.5V, I_D @4A<60m Ω
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN5060-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0028 ounces, 0.08 grams



Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

16 A

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	60		
Gate-Source Voltage		V _{GS}	<u>+</u> 20	V	
Continuous Drain Current (Note 4)	T _C =25°C		16		
	T _C =100°C	ID	10	А	
Pulsed Drain Current (Note 1)	T _C =25°C	I _{DM}	64		
Power Dissipation	T _C =25°C	D.	32.6		
	T _C =100°C	PD	16.3	W	
Continuous Drain Current (Note 4)	T _A =25°C		4.4		
	T _A =70°C	ID	3.5	A	
Power Dissipation	T _A =25°C	D.	2.4		
	T _A =70°C	PD	1.6	W	
Single Pulse Avalanche Energy (Note 6)		E _{AS}	11	mJ	
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~175	°C	
Typical Thermal Resistance (Note 4,5)	Junction to Case	R _{θJC}	4.6	90.044	
	Junction to Ambient	R _{θJA}	62.5	°C/W	



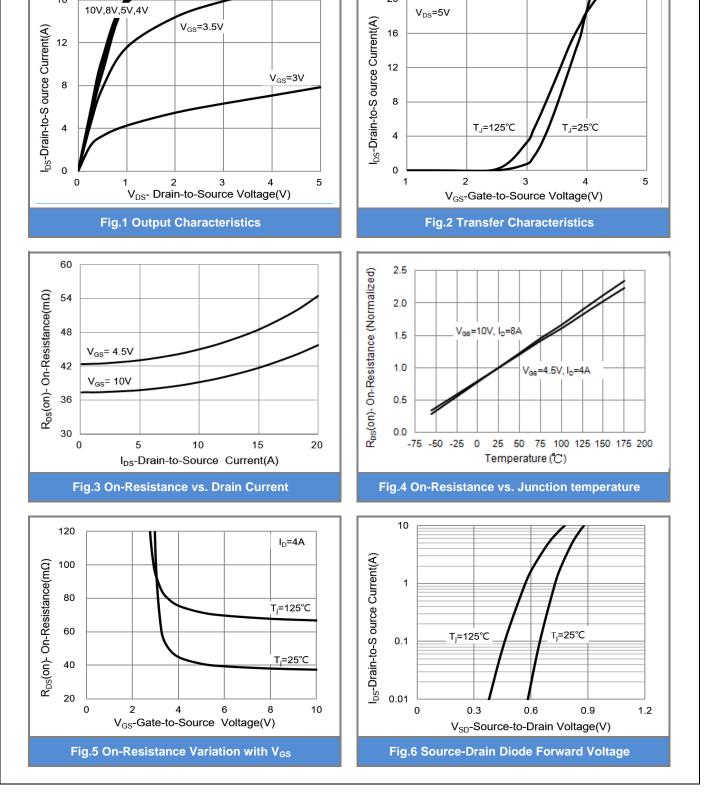
Electrical Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{DSS} V _{GS} =0V, I _D =250uA	60	-	-	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	1	1.77	2.5	V
Drain-Source On-State Resistance	R _{DS(on)}	V_{GS} =10V, I_{D} =8A	-	37	50	mΩ
		V _{GS} =4.5V, I _D =4A	-	42	60	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 7)		·				
Total Gate Charge	Qg	V _{DS} =30V, I _D =4A, V _{GS} =10V ^(Note 2,3)	-	14	-	nC
Gate-Source Charge	Q _{gs}		-	2.9	-	
Gate-Drain Charge	Q _{gd}		-	2.3	-	
Input Capacitance	Ciss	V _{DS} =15V, V _{GS} =0V,	-	815	-	pF
Output Capacitance	Coss		-	379	-	
Reverse Transfer Capacitance	Crss	f=1MHZ	-	110	-	
Turn-On Delay Time	td _(on)	V _{DD} =30V, I _D =1A, V _{GS} =10V, R _G =3.3Ω (Note 2,3)	-	3.9	-	ns
Turn-On Rise Time	tr		-	13	-	
Turn-Off Delay Time	td _(off)		-	23	-	
Turn-Off Fall Time	t _f		-	6.7	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	16	A
Diode Forward Current	I _S					
Diode Forward Voltage	V _{SD}	I _S =1A, V _{GS} =0V	-	0.73	1	V

NOTES :

- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH, $I_{\text{AS}}{=}15\text{A},\,V_{\text{DD}}{=}25\text{V},\,V_{\text{GS}}{=}10\text{V}.$
- 7. Guaranteed by design, not subject to production testing.

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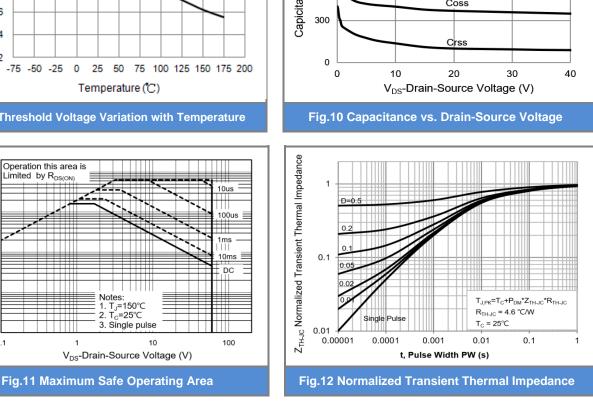
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PJQ5458A-AU

TYPICAL CHARACTERISTIC CURVES

16

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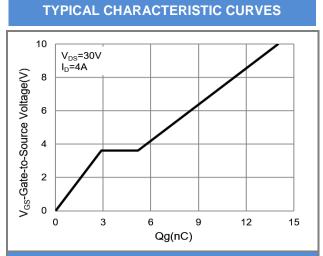


Fig.7 Gate-Charge Characteristics

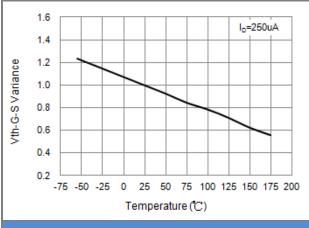
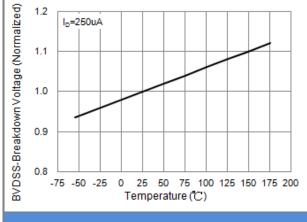
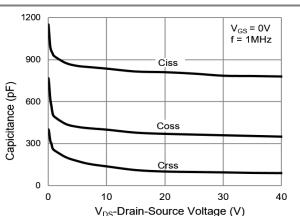


Fig.9 Threshold Voltage Variation with Temperature







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100

10

1

0.1

0.01

0.1

1

Drain-to-S ource Current - I_D (A)

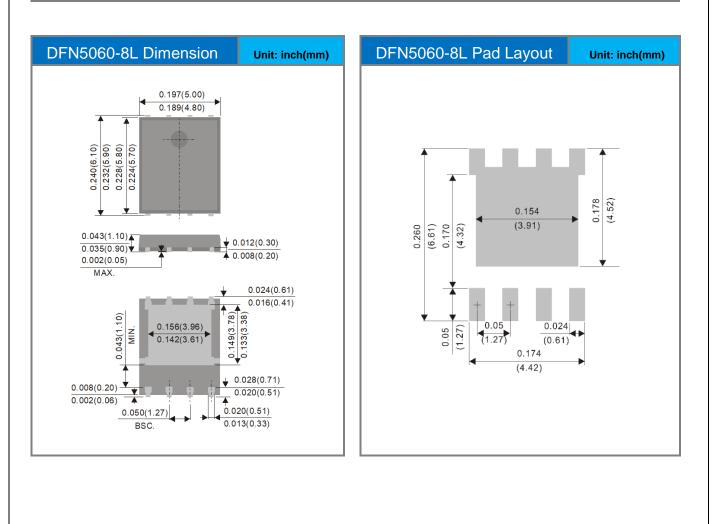




Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJQ5458A-AU_R2_000A1	DFN5060-8L	3000pcs / 13" reel	Q5458A	Halogen free

Packaging Information & Mounting Pad Layout





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